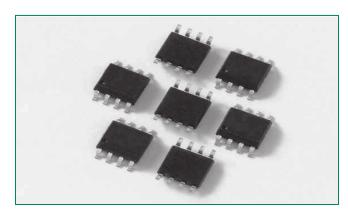
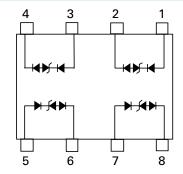
## **TVS Diode Arrays** (SPA™ Family of Products)

Lightning Surge Protection - SPLV2.8-4 Series

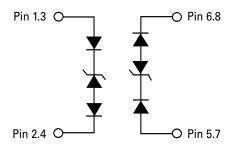
## SPLV2.8-4 Series 2.8V 40A TVS Array



#### **Pinout**



### **Functional Block Diagram**



#### NOT RECOMMENDED FOR NEW DESIGNS

SPLV2.8-4BTG is eventually going to be replaced by the SLVU2.8-4BTG TVS Diode Array with identical form, fit, and function. Please use this device for new or future designs and more detail can be found on Littelfuse.com

TALLITUSE®

GREEN

The SPLV2.8-4 was designed to protect low voltage, CMOS devices from ESD and lightning induced transients. There is a compensating diode in series with each low voltage TVS to present a low loading capacitance to the line being protected. These robust structures can safely absorb repetitive ESD strikes at ±30kV (contact discharge) per IEC61000-4-2 standard and each structure can safely dissipate up to 40A (IEC61000-4-5, t<sub>p</sub>=8/20µs) with very low clamping voltages.

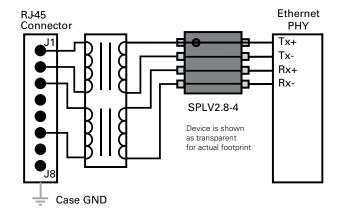
## **Features**

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 40A (8/20µs)
- Low capacitance of 2pF per line
- · Low leakage current of 1µA (MAX) at 2.8V
- SOIC-8 pin (JEDEC MS-012) configuration allows for simple flow-through layout

## **Applications**

- 10/100/1000 Ethernet
- WAN/LAN Equipment
- Switching Systems
- Desktops, Servers, and Notebooks
- Analog Inputs
- Base Stations

## **Application Example**



# TVS Diode Arrays (SPA™ Fa

Lightning Surge Protection - SPLV2.8

## NOT RECOMMENDED FOR NEW DESIGNS

SPLV2.8-4BTG is eventually going to be replaced by the SLVU2.8-4BTG TVS Diode Array with identical form, fit, and function. Please use this device for new or future designs and more detail can be found on Littelfuse.com

## **Electrical Characteristics (T<sub>OP</sub> = 25°C)**

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V <sub>RWM</sub>	I <sub>R</sub> ≤1μA			2.8	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>τ</sub> =2μΑ	3.0			V
Snap Back Voltage	V <sub>SB</sub>	I <sub>T</sub> =50mA	2.8			V
Reverse Leakage Current	I <sub>LEAK</sub>	V <sub>R</sub> =2.8V (Each Line)			1	μΑ
Clamping Voltage <sup>1</sup>	V <sub>C</sub>	I <sub>pp</sub> =5A, t <sub>p</sub> =8/20μs (Each Line)		7.0	8.5	V
Clamping Voltage <sup>1</sup>	V <sub>C</sub>	I <sub>PP</sub> =24A, t <sub>P</sub> =8/20μs (Each Line)		13.9	15.0	V
ESD Withstand Voltage <sup>1</sup>	V <sub>ESD</sub>	IEC61000-4-2 (Contact)	±30			kV
		IEC61000-4-2 (Air)	±30			kV
Dynamic Resistance	R <sub>DYN</sub>	(V <sub>C2</sub> - V <sub>C1</sub> ) / (I <sub>PP2</sub> - I <sub>PP1</sub> ) (Each Line)		0.4		Ω
Diode Capacitance <sup>1</sup>	C <sub>D</sub>	V <sub>R</sub> =0V, f=1MHz (Each Line)		2.0	2.5	pF

Note: <sup>1</sup>Parameter is guaranteed by design and/or device characterization.

Abso	lute l	Maximum	Ratings

Parameter	Rating	Units
Peak Pulse Power (t <sub>p</sub> =8/20µs)	600	W
Peak Pulse Current (t <sub>p</sub> =8/20µs)	40	А
Operating Temperature	-40 to 85	°C
Storage Temperature	-60 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Figure 1: Capacitance vs. Reverse Voltage

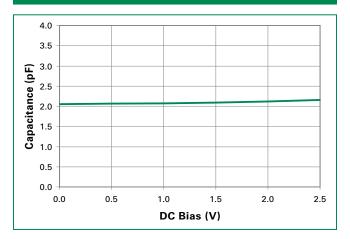


Figure 2: Clamping Voltage vs. I<sub>PP</sub>

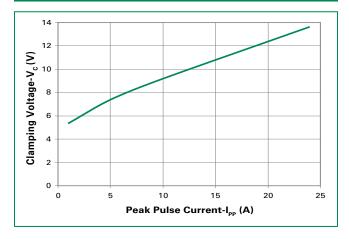
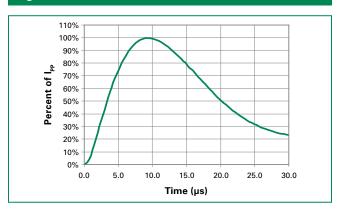


Figure 3: Pulse Waveform



## TVS Diode Arrays (SPA™ Family of Products)

Lightning Surge Protection - SPLV2.8-4 Series

## NOT RECOMMENDED FOR NEW DESIGNS

elfuse

SPLV2.8-4BTG is eventually going to be replaced by the SLVU2.8-4BTG TVS Diode Array with identical form, fit, and function. Please use this device for new or future designs and more detail can be found on Littelfuse.com

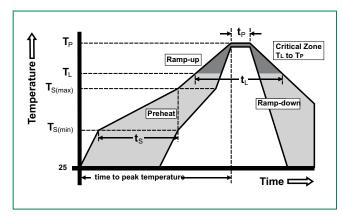
## **Product Characteristics**

Lead Plating	Matte Tin
Lead Material	Copper Alloy
Lead Coplanarity	0.0004 inches (0.102mm)
Substitute Material	Silicon
Body Material	Molded Epoxy
Flammability	UL 94 V-0

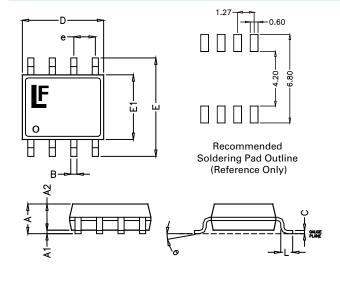
- All dimensions are in millimeters
   Dimensions include solder plating.
- 3. Dimensions are exclusive of mold flash & metal burr.
- Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
   Package surface matte finish VDI 11-13.

## Soldering Parameters

Reflow Condition		Pb – Free assembly	
	-Temperature Min (T <sub>s(min)</sub> )	150°C	
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200°C	
	-Time (min to max) (t <sub>s</sub> )	60 – 180 secs	
Average ra	amp up rate (Liquidus) Temp k	5°C/second max	
T <sub>S(max)</sub> to T <sub>L</sub>	- Ramp-up Rate	5°C/second max	
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
nellow	-Temperature (t <sub>L</sub> )	60 – 150 seconds	
PeakTemp	perature (T <sub>P</sub> )	260 <sup>+0/-5</sup> °C	
Time within 5°C of actual peak Temperature (t <sub>n</sub> )		20 - 40 seconds	
Ramp-down Rate		5°C/second max	
Time 25°C to peak Temperature (T <sub>P</sub> )		8 minutes Max.	
Do not exceed		260°C	



## Package Dimensions — Mechanical Drawings and Recommended Solder Pad Outline



Package	SOIC				
Pins	8				
JEDEC	MS-012				
	Millin	netres	Inches		
	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A1	0.10	0.25	0.004	0.010	
A2	1.25	1.65	0.050	0.065	
В	0.31	0.51	0.012	0.020	
C	0.17	0.25	0.007	0.010	
D	4.80	5.00	0.189	0.197	
E	5.80	6.20	0.228	0.244	
E1	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
L	0.40 1.27 0.016 0.		0.050		

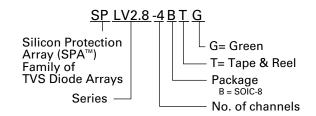
TVS Diode Arrays (SPAT Family of Products)

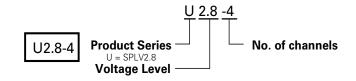
Lightning Surge Protection

## NOT RECOMMENDED FOR NEW DESIGNS

SPLV2.8-4BTG is eventually going to be replaced by the SLVU2.8-4BTG TVS Diode Array with identical form, fit, and function. Please use this device for new or future designs and more detail can be found on Littelfuse.com

## **Part Numbering System**

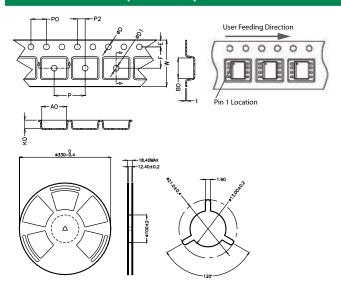




## **Ordering Information**

Part Number	Package	Marking	Min. Order Qty.
SPLV2.8-4BTG	SOIC-8	U2.8-4	2500

## **Embossed Carrier Tape & Reel Specification — SOIC Package**



Cymahal	Millimetres		Inches		
Symbol	Min	Max	Min	Max	
E	1.65	1.85	0.065	0.073	
F	5.4	5.6	0.213	0.22	
P2	1.95	2.05	0.077	0.081	
D	1.5	1.6	0.059	0.063	
D1	1.50 Min		0.059 Min		
P0	3.9	4.1	0.154	0.161	
10P0	40.0 +/- 0.20		1.574 +/- 0.008		
W	11.9	12.1	0.468	0.476	
P	7.9	8.1	0.311	0.319	
A0	6.3	6.5	0.248	0.256	
В0	5.1	5.3	0.2	0.209	
K0	2	2.2	0.079	0.087	
t	0.30 +/- 0.05		0.012 +	/- 0.002	